Thyristor Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Metal

Overall Length:

1.646 inches

Mounting Facility Quantity:

1

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

### **Overall Width Across Flats:**

Between 0.544 inches and 0.563 inches

Thread Size:

0.250 inches

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

600.0 repetitive peak reverse voltage and 720.0 nonrepetitive peak reverse voltage and 5.0 peak gate voltage

### **Current Rating Per Characteristic:**

16.00 amperes forward current, average absolute and 150.00 amperes peak forward surge current absolute

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

### **Special Features:**

Junction pattern arrangement: pnpn

### **Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

1 threaded stud and 2 tab, solder lug

### **Specification Data:**

81349-mil-prf-19500/108 government specification

#### Shelf Life:

N/a

### Unit Of Measure:

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## Demilitarization:

No

Fiig:

A110a0

# Mil-std (military Standard):

Mil-prf-19500 spec.